



# BCT4567A

## Low-Power, Dual SIM Card Analog Switch

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#### GENERAL DESCRIPTION

The BCT4567A is a QPDT switch with one common control inputs targeted at dual SIM card multiplexing. It is optimized for switching the WLAN-SIM data and control signals and dedicates one channel as a supply-source switch.

The BCT4567A is compatible with the requirements of SIM cards and feature a low on capacitance to ensure high speed data transfer, the VSIM switch path has a low RON characteristic to ensure minimal voltage drop in dual SIM card supply paths.

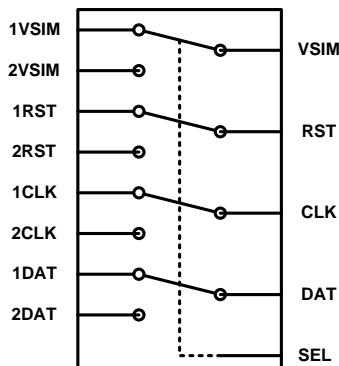
The device operates from a +1.65V to +5.0V supply and over the extended -40°C to +85°C temperature range. It is offered in 16-pin 3mm x 3mm TQFN package or 16-pin 2.6mm x 1.8mm QFN package.

#### APPLICATIONS

Dual SIM Card Switch  
Cell Phones  
Pad  
Digital Cameras  
PDAs  
Notebook

#### FEATURES

- Wide VCC Operating Range: 1.65 V to 5.0V
- Low On-Resistance  
Supply Path: 0.7Ω @VCC=2.7V  
Data Path: 3.3Ω @VCC=2.7V
- Low Power supply current: 1uA(MAX)
- Rail-to-Rail Signal Switching Range
- Fast Switching Speed: 20ns@VCC=3.3V
- Data Path -3dB bandwidth: 260MHz
- High Off Isolation: -68dB
- Crosstalk Rejection: -76dB
- Space-Saving, TQFN 3x3-16L or QFN 2.6x1.8-16L Package



LOGIC DIAGRAM

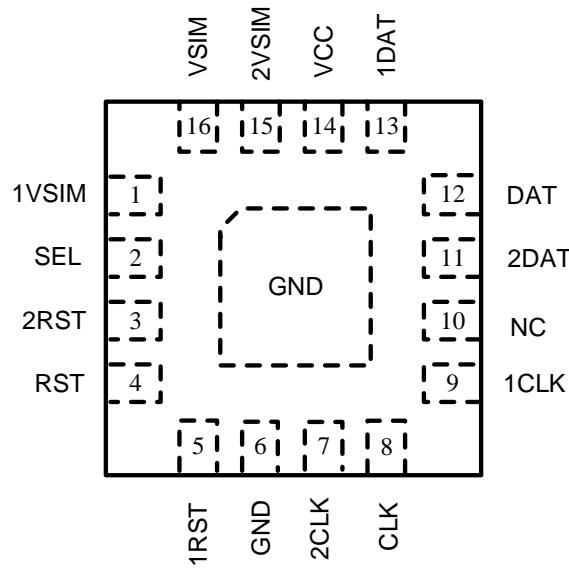
#### ORDERING INFORMATION

Ordering Code	Package Description	Temp Range	Top Marking	QTY/Reel
BCT4567AEGE-TR	TQFN3x3-16L	-40°C to +85°C	 4567A XXXXX	3000
BCT4567AEFE-TR	QFN2.6x1.8-16L	-40°C to +85°C	4567A XXXXX	3000

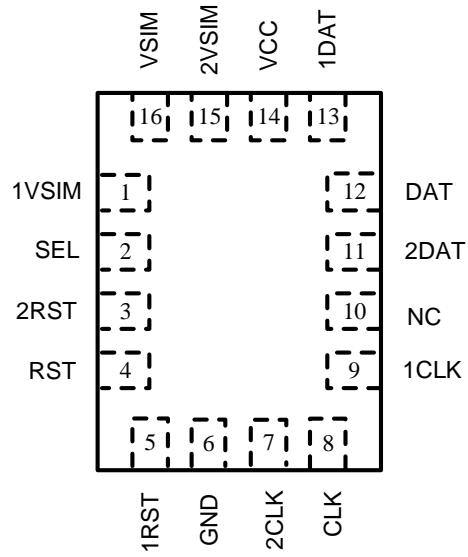
Mark Note:

1. "4567A" in Marking is Product code
2. "XXXXX" in Marking will be appeared as the batch code.

## Pin Configurations



TQFN3x3-16L



QFN2.6x1.8-16L

## Pin Description

Pin	Name	Function
1	1VSIM	SIM supply output 1
2	SEL	Select input
3	2RST	RST Normally Open Terminal
4	RST	RST Common Terminal
5	1RST	RST Normally Closed Terminal
6	GND	Ground
7	2CLK	CLK Normally Open Terminal
8	CLK	CLK Common Terminal
9	1CLK	CLK Normally Closed Terminal
10	NC	Not Connect
11	2DAT	DAT Normally Open Terminal
12	DAT	DAT Common Terminal
13	1DAT	DAT Normally Closed Terminal
14	VCC	Power Supply
15	2VSIM	SIM supply output 2
16	VSIM	SIM supply input



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### Truth Table

SEL	SWITCH STATE
0	1DAT = DAT, 1RST = RST, 1CLK = CLK, 1VSIM = VSIM
1	2DAT = DAT, 2RST = RST, 2CLK = CLK, 2 VSIM = VSIM

### Absolute Maximum Ratings

VCC, SEL to GND.....	-0.3V to +6.0V
All Other Pins to GND.....	-0.3V to (VCC + 0.3V)
SUPPLY SWITCH Continuous Current.....	±400mA
SUPPLY SWITCH Peak Current (pulsed at 1ms, 10% duty cycle) .....	±500mA
DATA SWITCH Continuous Current .....	±100mA
DATA SWITCH Peak Current (pulsed at 1ms, 10% duty cycle) .....	±120mA
Continuous Power Dissipation (TA = +70°C)	
TQFN3x3-16L (15.6mW/°C) .....	1.25W
QFN 2.6x1.8-16L (8.5mW/°C) .....	0.68W
Operating Temperature Range .....	-40°C to +85°C
Storage Temperature Range.....	-65°C to +150°C
Junction Temperature.....	+150°C
Lead Temperature (soldering, 10s) .....	+260°C
ESD HBM (human body model) .....	4KV

#### NOTE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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### Electrical Characteristics

(unless otherwise noted. Typical values are at VCC = 3.3V, TA = +25°C.) (2)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>POWER SUPPLY</b>						
Supply Voltage Range	VCC		1.65		5.0	V
Supply Current	ICC	V <sub>CNTRL</sub> = 0 or V <sub>CC</sub> , I <sub>OUT</sub> = 0			1	uA
<b>ANALOG SWITCH</b>						
Analog Signal Range	V <sub>SW</sub>	Switch I/O Voltage	0		VCC	V
VSIM On-Resistance	RON	I <sub>ON</sub> = -100 mA Figure 9	VCC= 1.8V V <sub>SW</sub> = 0, 1.8 V	0.8		Ω
			VCC= 2.7V V <sub>SW</sub> = 0, 2.3 V	0.7		
CLK, RST, DAT, On-Resistance	RON	I <sub>ON</sub> = -20 mA Figure 9	VCC= 1.8V V <sub>SW</sub> = 0, 1.8 V	4.0		Ω
			VCC= 2.7V V <sub>SW</sub> = 0, 2.3 V	3.3		
CLK, RST, DAT, On-Resistance Match	ΔRON	I <sub>ON</sub> = -20 mA Figure 9	VCC= 2.7V V <sub>SW</sub> = 0, 2.3 V	0.3		Ω
CLK, RST, DAT, On-Resistance Flatness	RFLAT	I <sub>ON</sub> = -20 mA Figure 9	VCC= 2.7V V <sub>SW</sub> = 0V to VCC	1.0		Ω
Off-Leakage Current	I <sub>OFF</sub>	VCC= 5.0V, nRST, nDAT, nCLK, nVSIM = 0 V to 5.0 V Figure 10	-1		1	uA
On-Leakage Current	I <sub>ON</sub>	VCC= 5.0V, RST, DAT, CLK, VSIM = 0 V to 5.0 V	-1		1	uA
<b>SEL DIGITAL INPUTS</b>						
Input-Logic High	V <sub>IH</sub>	VCC=1.65V to 5.0V		1.7		V
Input-Logic Low	V <sub>IL</sub>	VCC=1.65V to 5.0V			0.4	V
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 0 or VCC		-1	1	uA



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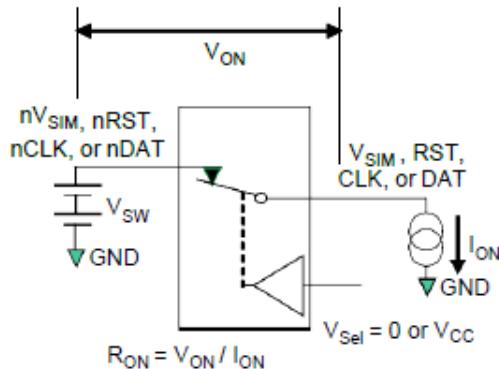
### Electrical Characteristics (continued)

(unless otherwise noted. Typical values are at  $V_{CC} = 3.3V$ ,  $T_A = +25^{\circ}C$ .) (2)

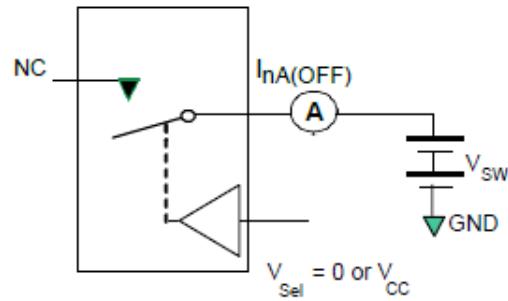
Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>DYNAMIC CHARACTERISTICS</b>						
Turn-On Time Sel to Output (DAT,CLK,RST)	$t_{ON}$	$R_L = 50 \Omega$ , $C_L = 35 \text{ pF}$ , $V_{SW} = 1.5 \text{ V}$ , Figure 11, Figure 12	$T_A = +25^{\circ}C$		20	30
			$T_A = T_{MIN} \text{ to } T_{MAX}$		50	ns
Turn-Off Time Sel to Output (DAT,CLK,RST)	$t_{OFF}$	$R_L = 50 \Omega$ , $C_L = 35 \text{ pF}$ , $V_{SW} = 1.5 \text{ V}$ , Figure 11, Figure 12	$T_A = +25^{\circ}C$		15	40
			$T_A = T_{MIN} \text{ to } T_{MAX}$		50	ns
Break-Before-Make Time (DAT,CLK,RST)	$t_{BBM}$	$R_L = 50 \Omega$ , $C_L = 35 \text{ pF}$ , $V_{SW1} = V_{SW2} = 1.5 \text{ V}$ , Figure 15	$T_A = +25^{\circ}C$	2	15	
			$T_A = T_{MIN} \text{ to } T_{MAX}$	2		ns
Charge Injection	$Q$	$C_L = 50 \text{ pF}$ , $R_{GEN} = 0 \Omega$ , $V_{GEN} = 0 \text{ V}$		100		pC
On-Channel Bandwidth -3dB (DAT,CLK,RST)	$BW$	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ Figure 16		260		MHz
Off-Isolation (DAT,CLK,RST)	$V_{ISO}$	$R_L = 50 \Omega$ , $f = 1\text{MHz}$ Figure 17		-68		dB
Crosstalk	$V_{CT}$	$R_L = 50 \Omega$ , $f = 1\text{MHz}$ Figure 18		-76		dB
RST, CLK, DAT Off Capacitance	$C_{OFF}$	$V_{CC} = 3.3 \text{ V}$ , Figure 19		7		pF
RST, CLK, DAT On Capacitance	$C_{ON}$	$V_{CC} = 3.3 \text{ V}$ , $f = 1 \text{ MHz}$ Figure 20		20		pF

Note 2: Devices are 100% tested at  $T_A = +25^{\circ}C$ . Limits across the full temperature range are guaranteed by design and correlation.

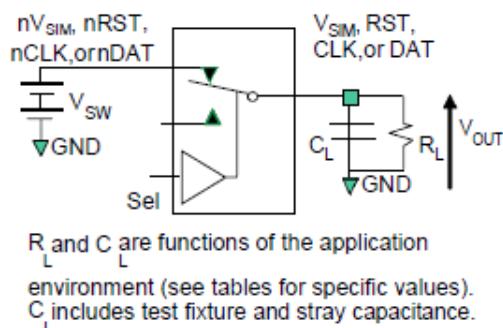
### Test Diagrams /Timing Diagrams



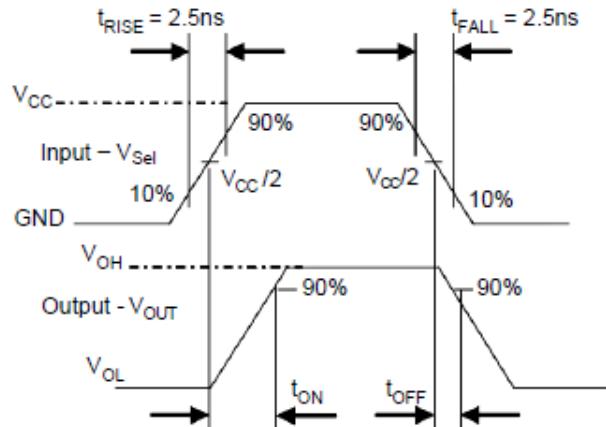
**Figure 9. On Resistance**



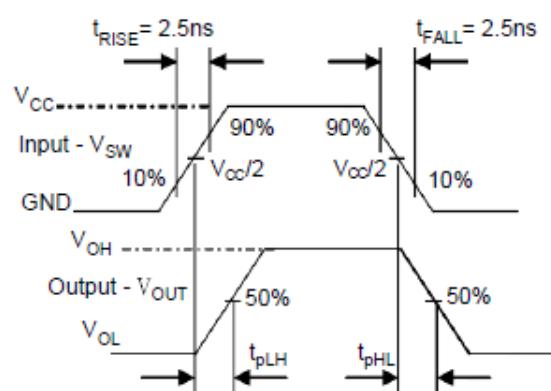
**Figure 10. Off Leakage**



**Figure 11. AC Test Circuit Load**



**Figure 12. Turn-On / Turn-Off Waveforms**



**Figure 13. Propagation Delay**

### Test Diagrams /Timing Diagrams

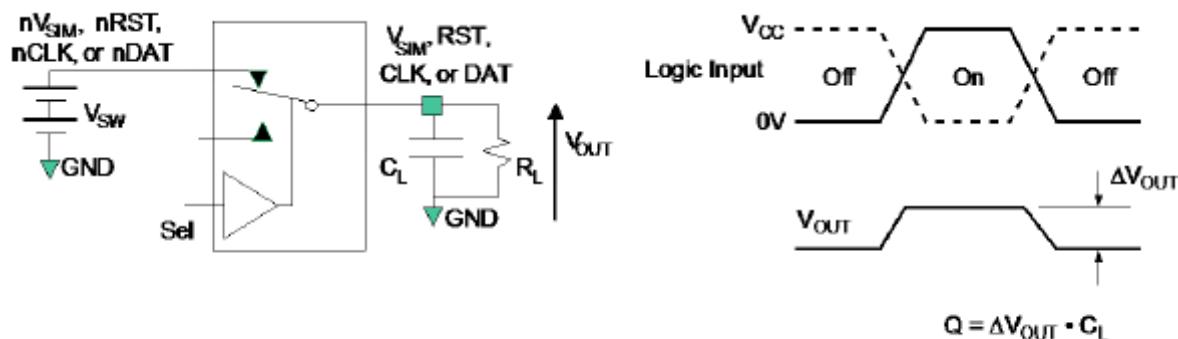
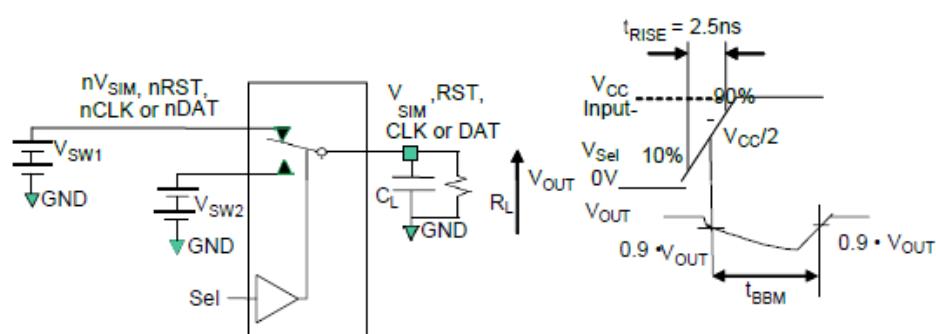
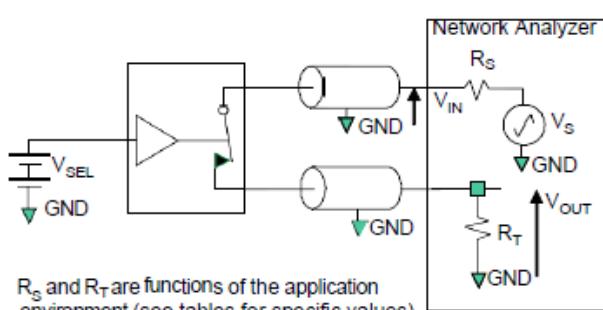


Figure 14. Charge Injection



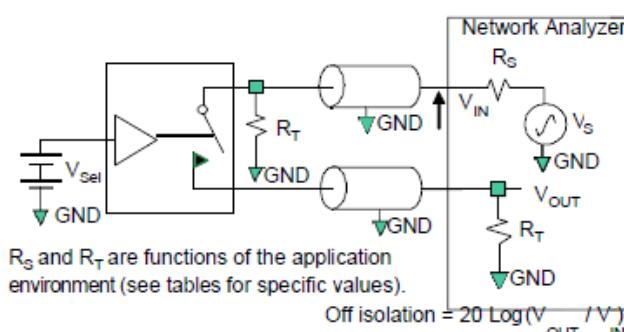
$R_L$  and  $C_L$  are functions of the application environment (see tables for specific values).  $C_L$  includes test fixture and stray capacitance.

Figure 15. Break-Before-Make Interval Timing



$R_s$  and  $R_T$  are functions of the application environment (see tables for specific values).

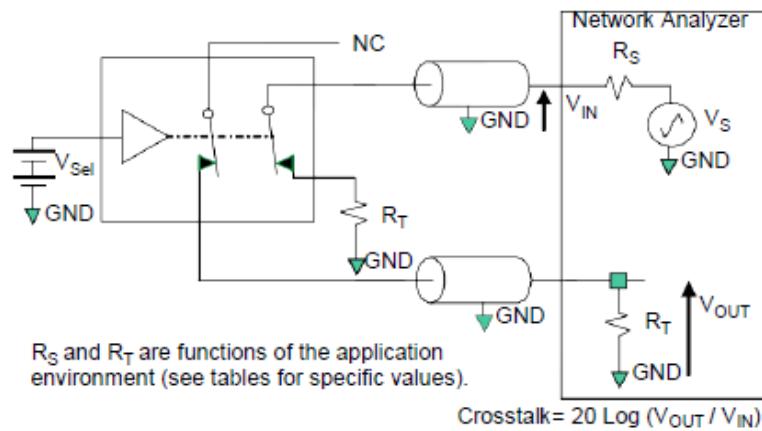
Figure 16. Bandwidth



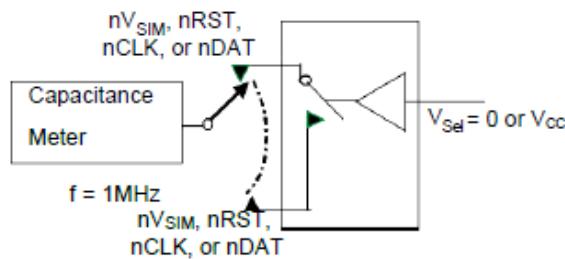
$R_s$  and  $R_T$  are functions of the application environment (see tables for specific values).

Figure 17. Channel Off Isolation

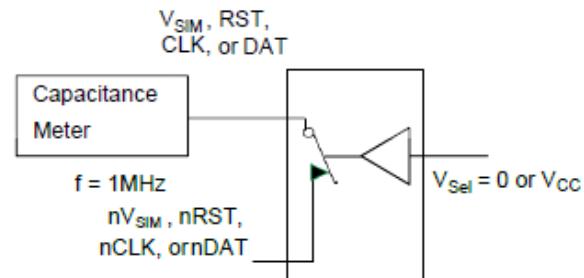
### Test Diagrams /Timing Diagrams



**Figure 18. Non-Adjacent Channel-to-Channel Crosstalk**



**Figure 19. Channel Off Capacitance**



**Figure 20. Channel On Capacitance**



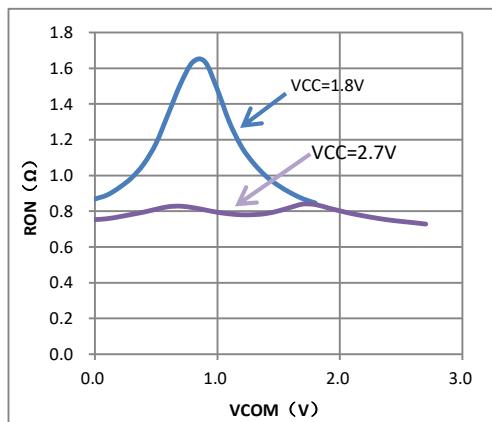
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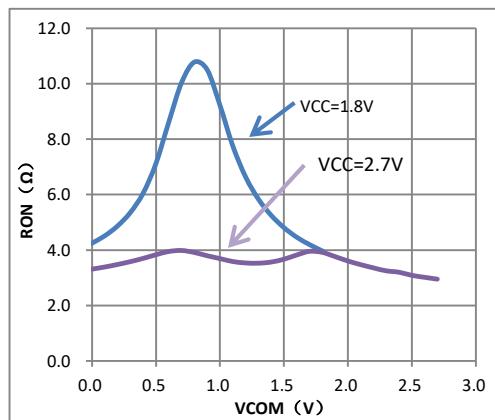
### Typical Operating Characteristics

(VCC = 3V, TA = +25°C, unless otherwise noted.)

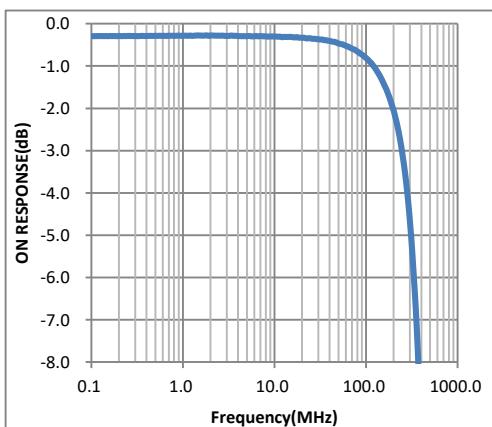
SUPPLY PATH ON-RESISTANCE



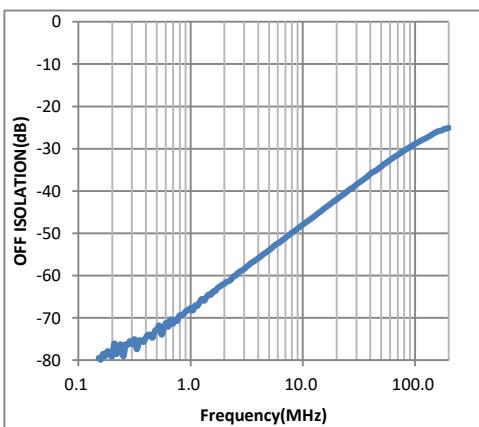
DATA PATH ON-RESISTANCE



ON-RESPONSE vs. FREQUENCY



OFF-ISOLATION vs. FREQUENCY

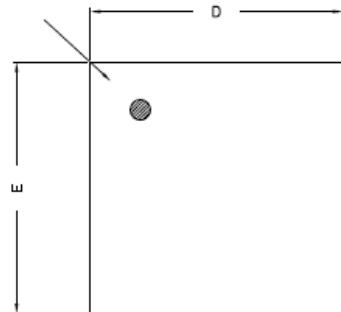




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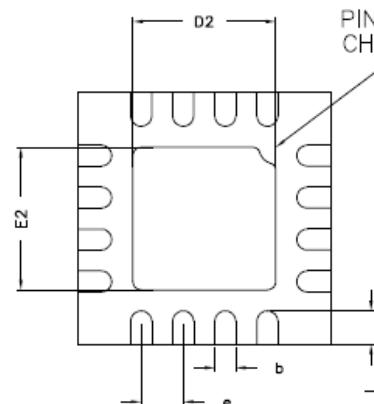
**PACKAGE OUTLINE DIMENSIONS: TQFN 3x3 -16L**

PIN 1 DOT  
BY MARKING

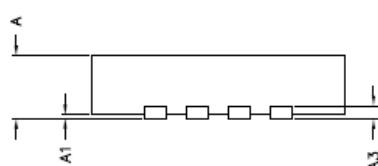


TOP VIEW

PIN #1 IDENTIFICATION  
CHAMFER



BOTTOM VIEW



SIDE VIEW

COMMON DIMENSIONS(MM)			
PKG.	W: VERY VERY THIN		
REF.	MIN.	NOM.	MAX
A	0.70	0.75	0.80
A1	0.00	—	0.05
A3	0.2 REF.		
D	2.95	3.00	3.05
E	2.95	3.00	3.05
b	0.18	0.25	0.30
L	0.30	0.40	0.50
D2	1.55	1.70	1.80
E2	1.55	1.70	1.80
e	0.5 BSC		

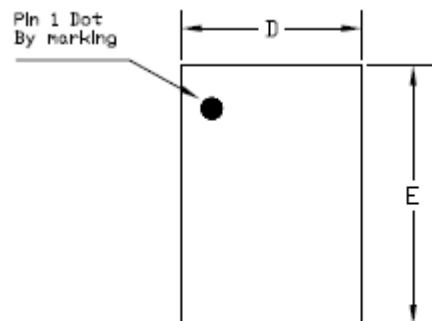


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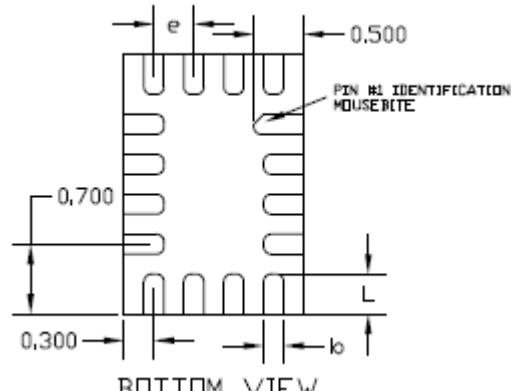
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### Analog Switch

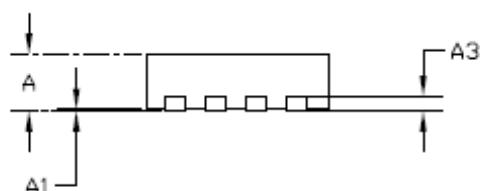
#### PACKAGE OUTLINE DIMENSIONS: QFN 2.6x1.8 -16L



TOP VIEW



BOTTOM VIEW



SIDE VIEW

COMMON DIMENSIONS(MM)			
PKG.	UT:ULTRA THIN		
REF.	MIN.	NOM.	MAX
A	>0.50	0.55	0.60
A1	0.00	-	0.05
A3	0.15 RFF.		
D	1.75	1.80	1.85
E	2.55	2.60	2.65
L	0.30	0.40	0.50
b	0.15	0.20	0.25
e	0.40 BSC		